NSN 5961-01-042-8172

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-042-8172 **Inclosure Material:** Glass **Overall Length:** 6.000 inches **Overall Height:** 1.000 inches **Overall Width:** 1.000 inches **Mounting Method:** Terminal **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 8000.0 reverse voltage, peak **Current Rating Per Characteristic:** 2.75 amperes forward current, average absolute **Maximum Operating Tempurature Per Measurement Point:** 140.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 turret Shelf Life: N/a **Unit Of Measure:**

Demilitarization:

No Fiig: A110a0